

Leading Innovation >>>

Toshiba Memory America, Inc.



Image may be representation. See specifications for product details.

TC58BVG2S0HTAI0

Part Number:	TC58BVG2S0HTAI0
Manufacturer/Brand:	Toshiba Memory America, Inc.
Product description	IC FLASH 4G PARALLEL 48TSOP I
Datasheets:	 TC58BVG2S0HTAI0.pdf
RoHs Status	 Lead free / RoHS Compliant
Stock Condition	19214 pcs stock
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

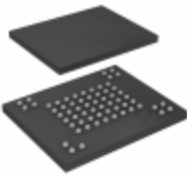
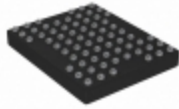
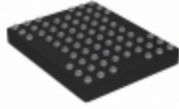
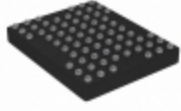
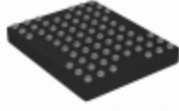
Specifications of TC58BVG2S0HTAI0

PART NUMBER	TC58BVG2S0HTAI0
MANUFACTURER	Toshiba Memory America, Inc.
DESCRIPTION	IC FLASH 4G PARALLEL 48TSOP I
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
QUANTITY AVAILABLE	19214 pcs
DATA SHEET	 TC58BVG2S0HTAI0.pdf
WRITE CYCLE TIME - WORD, PAGE	25ns
VOLTAGE - SUPPLY	2.7 V ~ 3.6 V
TECHNOLOGY	FLASH - NAND (SLC)
SUPPLIER DEVICE PACKAGE	48-TSOP I
SERIES	Benand™
PACKAGING	Tray
PACKAGE / CASE	48-TFSOP (0.724", 18.40mm Width)
OTHER NAMES	TC58BVG2S0HTAI0B4H TC58BVG2S0HTAI0YCJ
OPERATING TEMPERATURE	-40°C ~ 85°C (TA)
MOUNTING TYPE	Surface Mount
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Non-Volatile
MEMORY SIZE	4Gb (512M x 8)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	FLASH
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	FLASH - NAND (SLC) Memory IC 4Gb (512M x 8) Parallel 25ns 48-TSOP I
ACCESS TIME	25ns

Related Tags

Toshiba Memory America, Inc. TC58BVG2S0HTAI0	TC58BVG2S0HTAI0 Distributor	TC58BVG2S0HTAI0 Supplier
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TC58BVG2S0HTAI0 PDF Datasheet	TC58BVG2S0HTAI0 Download Datasheet	TC58BVG2S0HTAI0 Datasheet
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Related Products

Leading Innovation >>> TC58BYG0S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: 1GB SLC NAND BGA 24NM I TEMP (EE) In stock: 27190 pcs RFQ	 TC58BVG2S0HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G PARALLEL 63TFBGA In stock: 17495 pcs RFQ
Leading Innovation >>> TC58BVG1S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: 2GB SLC BENAND 24NM BGA 9X11 (EE) In stock: 27064 pcs RFQ	 TC58BVG1S3HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 2G PARALLEL 67VFBGA In stock: 26100 pcs RFQ
Leading Innovation >>> TC58BYG1S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: 2GB SLC NAND BGA 24NM I TEMP (EE) In stock: 21534 pcs RFQ	 TC58BYG1S3HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 2G PARALLEL 67VFBGA In stock: 24557 pcs RFQ
 TC58BVG1S3HTAI0 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 2G PARALLEL 48TSOP I In stock: 26928 pcs RFQ	 TC58BVG1S3HTA00 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 2G PARALLEL 48TSOP I In stock: 25917 pcs RFQ
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 TC58BYG0S3HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G PARALLEL 67VFBGA In stock: 30613 pcs RFQ	 TC58BYG2S0HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G PARALLEL 67VFBGA In stock: 16088 pcs RFQ